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ONS00187  
09/917,731

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

*del Auth A*  
*A.I.*  
*12/26/02*

~~In re~~ Application of: Imam, Mohamed et al.

~~Serial No.:~~ 09/917,731

~~Filing Date:~~ July 31, 2001

~~Group Art Unit:~~ 2812

~~Examiner:~~ Roman, Angel

~~Title:~~ METHOD FOR MANUFACTURING A HIGH  
VOLTAGE MOSFET SEMICONDUCTOR  
DEVICE WITH ENHANCED CHARGE  
CONTROLLABILITY

FAX COPY RECEIVED

DEC 05 2002

TECHNOLOGY CENTER 2800

I HEREBY CERTIFY THAT THIS CORRESPONDENCE IS BEING FACSIMILE  
TRANSMITTED TO THE PATENT AND TRADEMARK OFFICE, ATTN EXAMINER  
Roman, Angel AT THE FAX NO. (703) 872-9318

ON:

December 5, 2002

Date of Facsimile Transmission

Lydia McNamara

Name of Person Signing Certificate

15 pages total

Lydia McNamara

SIGNATURE

12/5/02

DATE

Honorable Commissioner of Patents,  
Washington, D.C. 20231

AMENDMENT

SIR:

In response to the office action of July 18, 2002,  
please amend the above-identified application as follows.